Diode Semiconductor Device - Page 1 of 1



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Inclosure Material	
Glass	
Overall Length:	
0.185 inches	
Terminal Length:	
1.300 inches	
Overall Diameter:	
0.140 inches	
Function For Whic	h Designed:
Transient suppress	pr
Mounting Method:	
Terminal	
Features Provided	:
Hermetically sealed	case and quality assurance level tx
Semiconductor Ma	iterial:
Silicon	
Voltage Rating In	/olts Per Characteristic:
15.75 breakdown v	oltage, dc
Voltage Tolerance	In Percent:
-5.0/+5.0	
Current Rating Pe	Characteristic:
20.00 microampere	s forward current, average peak
Power Rating Per	Characteristic:
500.0 watts small-s	gnal input power, common-collector major
Maximum Operatii	ng Tempurature Per Measurement Point:
150.0 degrees celsi	us ambient air
Test Data Docume	nt:
81349-mil-s-19500	specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificatio
format; excludes co	ommercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And	I Quantity:
2 uninsulated wire l	ead
Specification Data	
81349-mil-s-19500/	516 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig: A110a0	